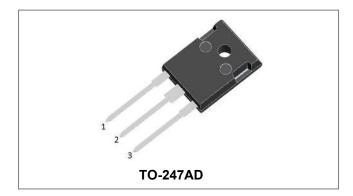


MBR60100WT

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MBR60100WT SCHOTTKY RECTIFIER



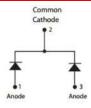
Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Circuit Diagram



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=135°C, rectangular wave form	30(Per Leg) 60(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse,Tc=25°C	280	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 30A, Pulse, TJ = 25℃	0.82	0.90	V
(Per Leg)*	V _{F2}	@ 30A, Pulse, T _J = 125℃	0.69	0.81	V
Reverse Current	I _{R1}	@V _R = rated V _R ,T _J = 25 $^{\circ}$ C	0.0004	1.0	mA
(Per Leg)*	I _{R2}	@V _R = rated V _R ,T _J = 125 $^{\circ}$ C	0.3	20	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25℃, f _{SIG} = 1MHz	1000	1200	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 $\mu s, \ duty \ cycle < 2\%$

http://www.smc-diodes.com - sales@ smc-diodes.com •



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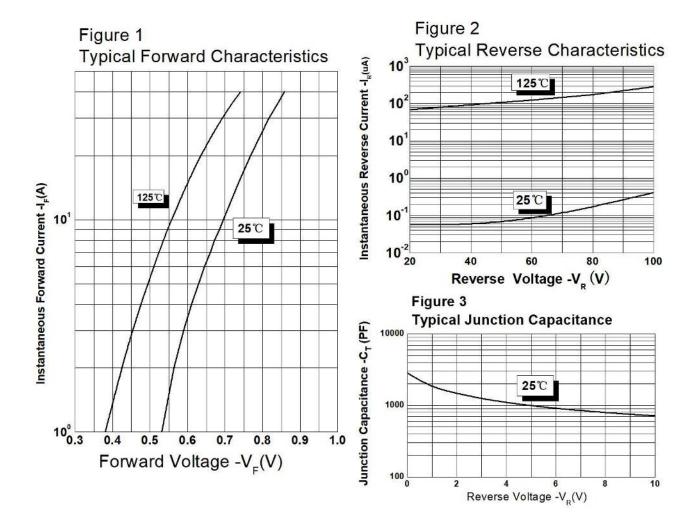


RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.5	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

Ratings and Characteristics Curves



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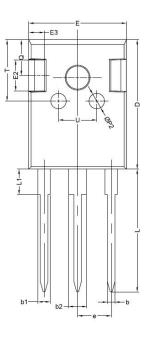


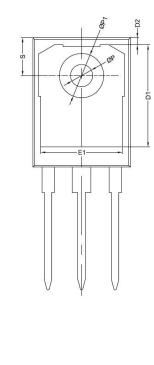
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Mechanical Dimensions TO-247AD





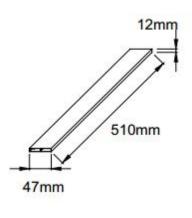
CYMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.40	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
с	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.55		
D2		1.20		
E	15.45	15.80	16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.70	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1		7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
Т		10.00		
U		6.20		

Ordering Information:

IT T

Device	Package	Shipping
MBR60100WT	TO-247AD(Pb-Free)	25pcs / tube

Tube Specification



A1

Marking Diagram



Where XXXXX is YYWWL

MBR

SSG

YY WW

L

60 100 WT

=	Device	Туре

- = Forward Current (60A)
- = Reverse Voltage (100V) = Configuration
- = SSG = Year
- - = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

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